

LED ARRAY



LA16B/YG-S34-PF

DATA SHEET

- DOC. NO : QW0905-LA16B/YG-S34-PF
- REV. : A
- DATE : 14 Oct. 2006







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Absolute Maximum Ratings at Ta=25 $^\circ\!\mathrm{C}$

Deremeter	Symbol	Rati	UNIT	
Parameter	Symbol	Y	G	UNIT
Forward Current	lF	20	30	mA
Peak Forward Current Duty 1/10@10KHz	IFP	80	120	mA
Power Dissipation	PD	60	100	mW
Reverse Current @5V	lr	1	μ A	
Operating Temperature	Topr	-40 ~	°C	
Storage Temperature	Tstg	-40 ~	°C	

Typical Electrical	& Optical	Characteristics	(Ta=25	°C)
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PART NO	MATERIAL	COLOR		Peak wave length λ Pnm	Spectral halfwidth $\triangle \lambda$ nm	Forward voltage @20mA(V)		Luminous intensity @10mA(mcd)		Viewing angle 2 ∂ 1/2 (deg)
		Emitted	Lens			Min.	Max.	Min.	Тур.	
	GaAsP/GaP	Yellow	White Diffused	585	35	1.7	2.6	1.8	4.0	100
LA16B/YG-S34-PF	GaP	Green		565	30	1.7	2.6	1.8	4.0	100

Note : 1.The forward voltage data did not including $\pm 0.1V$ testing tolerance. 2. The luminous intensity data did not including $\pm 15\%$ testing tolerance.



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Typical Electro-Optical Characteristics Curve

Y CHIP



Fig.3 Forward Voltage vs. Temperature



Fig.5 Relative Intensity vs. Wavelength



Fig.2 Relative Intensity vs. Forward Current



Fig.4 Relative Intensity vs. Temperature



Ambient Temperature(°C)



Fig.2 Relative Intensity vs. Forward Current

3.5

3.0

2.5 2.0

1.5 1.0

0.5 0.0

1.0

Vormalize @20mA

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Typical Electro-Optical Characteristics Curve

G CHIP



Fig.3 Forward Voltage vs. Temperature



Forward Current(mA)

10

100









Ambient Temperature(°C)

1000



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Note: 1.Wave solder should not be made more than one time. 2.You can just only select one of the soldering conditions as above.



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Reliability Test:

Test Item	Test Condition	Description	Reference Standard	
Operating Life Test	1.Under Room Temperature 2.If=20mA 3.t=1000 hrs (-24hrs, +72hrs)	This test is conducted for the purpose of detemining the resistance of a part in electrical and themal stressed.	MIL-STD-750: 1026 MIL-STD-883: 1005 JIS C 7021: B-1	
High Temperature Storage Test	1.Ta=105 ℃±5℃ 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of high temperature for hours.	MIL-STD-883:1008 JIS C 7021: B-10	
Low Temperature Storage Test	1.Ta=-40 ℃±5℃ 2.t=1000 hrs (-24hrs, +72hrs)	The purpose of this is the resistance of the device which is laid under condition of low temperature for hours.	JIS C 7021: B-12	
High Temperature High Humidity Test	1.Ta=65 ℃±5℃ 2.RH=90 %~95% 3.t=240hrs ±2hrs	The purpose of this test is the resistance of the device under tropical for hours.	MIL-STD-202:103B JIS C 7021: B-11	
Thermal Shock Test	1.Ta=105 ℃ ±5 ℃ &-40 ℃ ±5 ℃ (10min) (10min) 2.total 10 cycles	The purpose of this is the resistance of the device to sudden extreme changes in high and low temperature.	MIL-STD-202: 107D MIL-STD-750: 1051 MIL-STD-883: 1011	
Solder Resistance Test	1.T.Sol=260 ℃±5℃ 2.Dwell time= 10 ±1sec.	This test intended to determine the thermal characteristic resistance of the device to sudden exposures at extreme changes in temperature when soldering the lead wire.	MIL-STD-202: 210A MIL-STD-750: 2031 JIS C 7021: A-1	
Solderability Test	1.T.Sol=230 ℃±5℃ 2.Dwell time=5±1sec	This test intended to see soldering well performed or not.	MIL-STD-202: 208D MIL-STD-750: 2026 MIL-STD-883: 2003 JIS C 7021: A-2	